

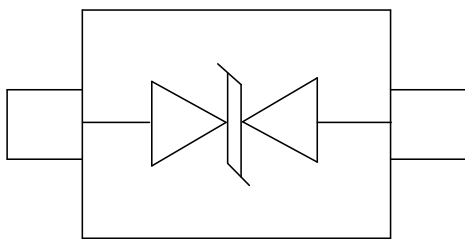
Description

The DC0521D9L is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast re-sponse time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The DC0521D9L complies with the IEC 61000-4-2 (ESD) with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into an ultra-small 1.0x0.6x0.4mm lead-free SOD-923 package. The small size and high ESD surge protection make DC0521D9L an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Mechanical Characteristics

- ◆ Package: SOD-923
- ◆ Lead Finish: Matte Tin
- ◆ Case Material: "Green" Molding Compound.
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Terminal Connections: See Diagram Below
- ◆ Marking Information: See Below

Dimensions and Pin Configuration



Circuit and Pin Schematic

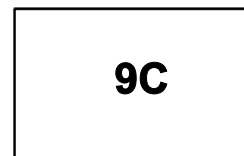
Features

- ◆ Protects one data or power line
- ◆ Ultra low leakage: nA level
- ◆ Operating voltage: 5V
- ◆ Low clamping voltage
- ◆ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 20\text{kV}$
 - Contact discharge: $\pm 20\text{kV}$
 - IEC61000-4-5 (Lightning) 5.5A (8/20 μs)
- ◆ RoHS Compliant

Applications

- ◆ Cellular Handsets and Accessories
- ◆ Personal Digital Assistants
- ◆ Notebooks and Handhelds
- ◆ Portable Instrumentation
- ◆ Digital Cameras
- ◆ Peripherals
- ◆ Audio Players
- ◆ Keypads, Side Keys, LCD Displays

Marking Information



Ordering Information

Part Number	Marking	Packaging	Reel Size
DC0521D9L	9C	8000/Tape & Reel	7 inch

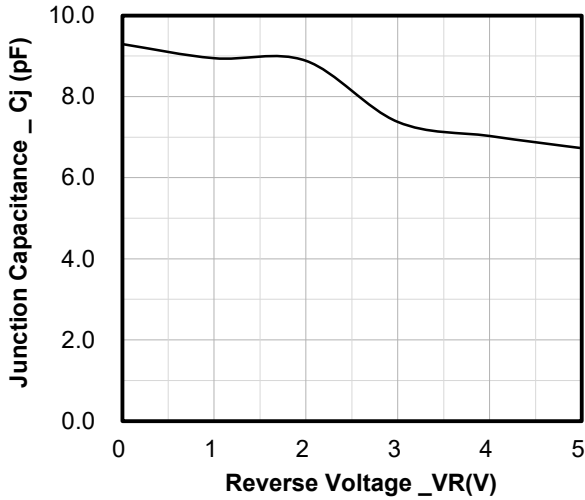
Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	Ppk	60	W
Peak Pulse Current (8/20 μs)	I _{PP}	5.5	A
ESD per IEC 61000-4-2 (Air)	V _{ESD}	± 20	kV
ESD per IEC 61000-4-2 (Contact)		± 20	
Operating Temperature Range	T _J	-55 to +125	$^\circ\text{C}$
Storage Temperature Range	T _{stg}	-55 to +150	$^\circ\text{C}$

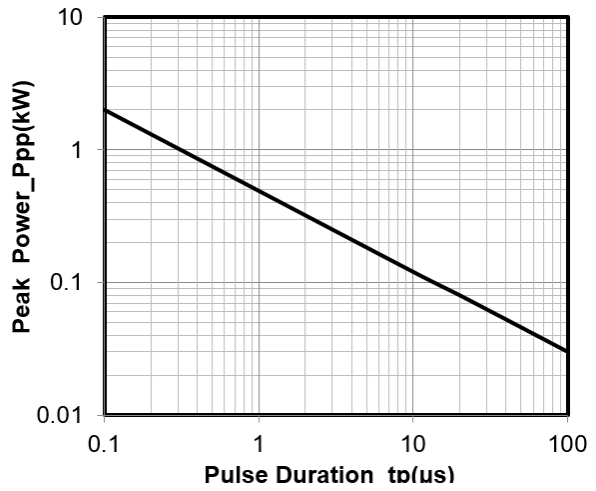
Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			5	V	
Breakdown Voltage	V _{BR}	5.6		8	V	I _T = 1mA
Reverse Leakage Current	I _R			0.2	μA	V _{RWM} = 5V
Clamping Voltage	V _C			8.5	V	I _{PP} = 1A
Clamping Voltage	V _C		9.5	12	V	I _{PP} = 5.5A
Junction Capacitance	C _J		10	15	pF	V _R = 0V, f = 1MHz

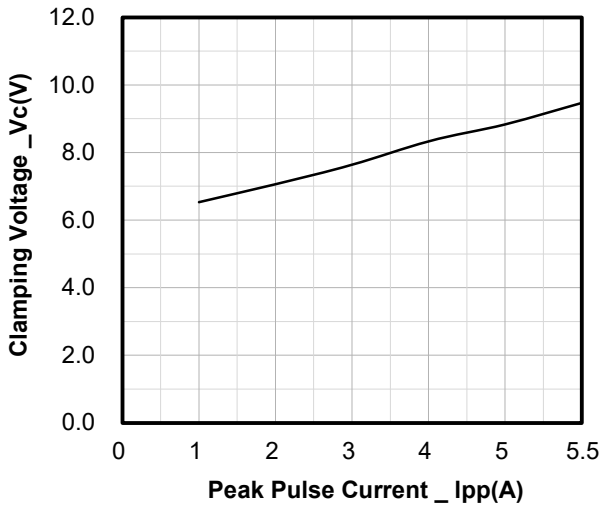
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



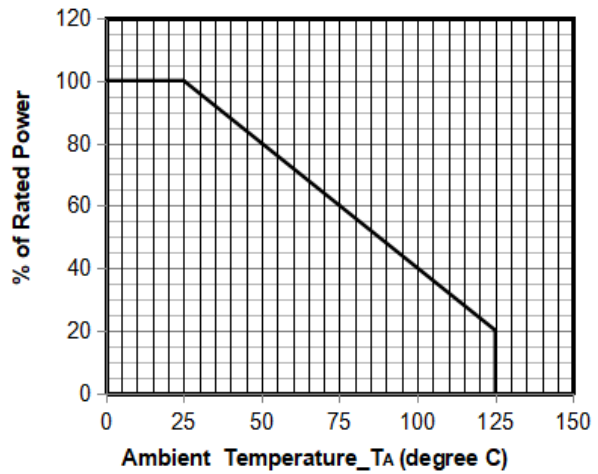
Junction Capacitance vs. Reverse Voltage



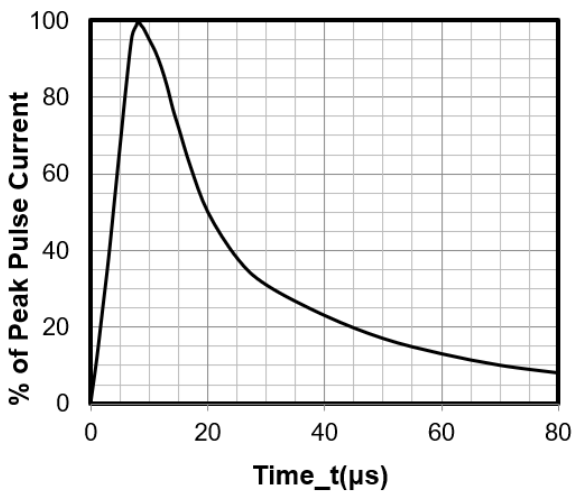
Peak Pulse Power vs. Pulse Time



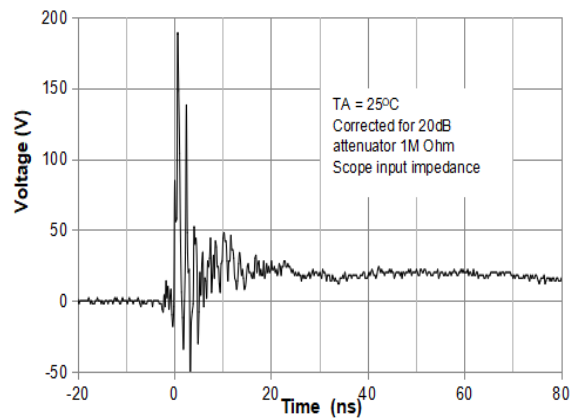
Clamping Voltage vs. Peak Pulse Current (tp = 8/20μs)



Power Derating Curve

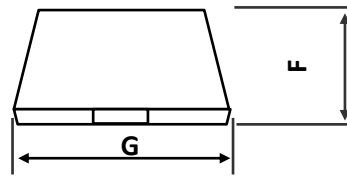
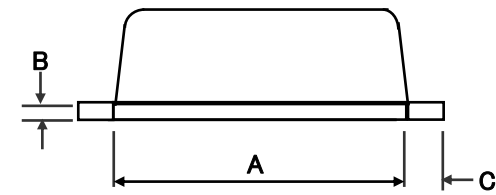


8 X 20μs Pulse Waveform



ESD Clamping Voltage
8 kV Contact per IEC61000-4-2

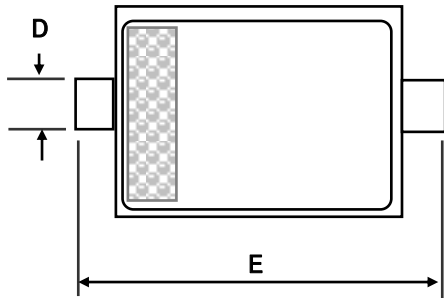
SOD-923 Package Outline Drawing



Dimensions

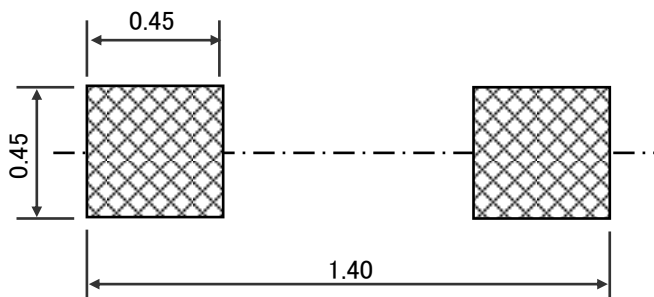
Unit	A	B	C	D	E	F	G
Max.	0.90	0.20	0.15	0.30	1.10	0.45	0.65
Min.	0.70	0.05	0.05	0.15	0.90	0.39	0.55

Unit: mm



SOD923 * Package Outline

Suggested Land Pattern



Contact Information

Changzhou D-first Electronics CO.,Ltd.

www.first-electronic.com

Email: xhf@first-electronic.cn

Phone: +86 (0519) 8817 1671